

SEARCHED

Class	Sub.	Date	Exmr.
257	288 327 402 405 410 411	7/13/02	A.M
458	267 585 591 778 785 786		
438	216 287 591 785	8/08/03	A.M
257	324 296 387 411		

SEARCH NOTES (INCLUDING SEARCH STRATEGY)

IEEE: MOSFET + Ta ₂ S - Oxy-nitride	Date	Exmr.
EAST : US-PUB-EP	7/13/02	A.m
J.P. Derwent		
CCLS ; MOSFET + High-K or high permittivity - Zirconium and Hafnium and Oxy-nitride		
EAST (All) + Inventor v + Metal + Silicate + gate dielectric	8/07/03	A.M

INTERFERENCE SEARCHED

Class	Sub.	Date	Exmr.

(RIGHT OUTSIDE)